

STRUCTURE Silicon Monolithic Integrated Circuit

NAME OF PRODUCT DC-AC Inverter Control IC

TYPE **BD9883AF, BD9883FV**

FUNCTION • 36V High voltage process
 • 1ch control with Half-bridge
 • Lamp current and voltage sense feed back control
 • Sequencing easily achieved with Soft Start Control
 • Short circuit protection with Timer Latch
 • Under Voltage Lock Out
 • Mode-selectable the operating or stand-by mode by stand-by pin

○Absolute Maximum Ratings (Ta = 25°C)

| Parameter | Symbol | Limits | Unit |
|------------------------------|--------|------------------|------|
| Supply Voltage | Vcc | 30 | V |
| BST | BST | 36 | V |
| BST-ST Voltage Difference | BST-SW | 7 | V |
| Operating Temperature Range | Topr | -40~+85 | °C |
| Storage Temperature Range | Tstg | -55~+125 | °C |
| Power Dissipation | Pd | 550*1 (BD9883AF) | mW |
| | | 650*2 (BD9883FV) | |
| Maximum Junction Temperature | Tjmax | +125 | °C |

*1Pd derated at 5.5mW/°C for temperature above Ta = 25°C (When mounted on a PCB 70.0mm×70.0mm×1.6mm)

*2Pd derated at 6.5mW/°C for temperature above Ta = 25°C (When mounted on a PCB 70.0mm×70.0mm×1.6mm)

○Recommended operating condition

| Parameter | Symbol | Limits | Unit |
|---------------------------|--------|-----------|------|
| Supply voltage | Vcc | 6.0~22.0 | V |
| CT oscillation frequency | fcr | 20~150 | kHz |
| BST voltage | BST | 4.0~30.0 | V |
| BST-SW voltage difference | BST-SW | 4.0~6.0 | V |
| BCT oscillation frequency | fBCT | 0.10~0.50 | kHz |

Status of this document

The Japanese version of this document is the official specification.

Please use the translation version of this document as a reference to expedite understanding of the official version.

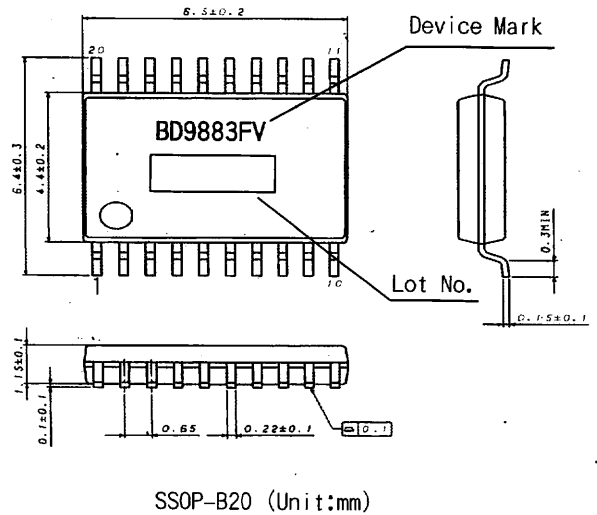
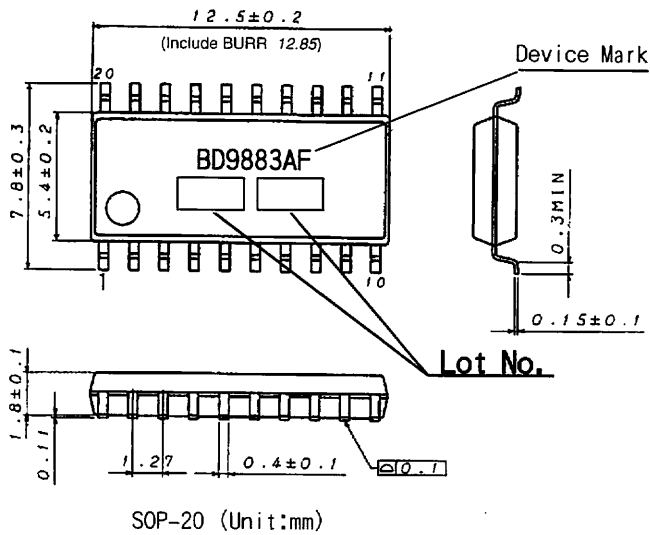
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○Electric Characteristics (Ta=25°C, VCC=7V)

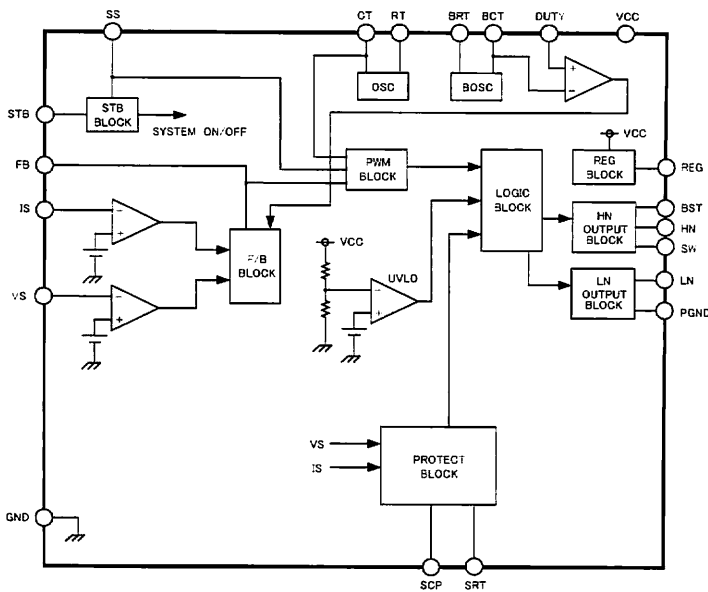
| Parameter | Symbol | Limits | | | Unit | Conditions |
|--------------------------------|-----------|---------|---------|---------|------|-----------------------|
| | | MIN. | TYP. | MAX. | | |
| ((WHOLE DEVICE)) | | | | | | |
| Operating current | Icc1 | — | 9.0 | 17.0 | mA | fCT=100kHz |
| Stand-by current | Icc2 | — | 5.0 | 10.0 | μA | |
| ((STAND BY CONTROL)) | | | | | | |
| Stand-by voltage H | VstH | 1.7 | — | VCC | V | System O N |
| Stand-by voltage L | VstL | -0.3 | — | 0.7 | V | System O F F |
| Stand-by hysteresis | ΔVst | 0.05 | 0.20 | 0.35 | V | |
| ((UVLO BLOCK)) | | | | | | |
| Operating voltage | VuvloH | 5.15 | 5.40 | 5.65 | V | |
| Shut down voltage | VuvloL | 4.90 | 5.15 | 5.40 | V | |
| ((REG BLOCK)) | | | | | | |
| REG output voltage | VREG | 5.30 | 5.50 | 5.70 | V | VCC > 6.0V |
| REG source current | IREG | 20.0 | — | — | mA | |
| ((OSC BLOCK)) | | | | | | |
| Active edge current | Iact | 1.35/RT | 1.5/RT | 1.65/RT | A | |
| Negative edge current | Ineg | Iact×10 | Iact×13 | Iact×16 | A | |
| OSC Max voltage | Vosch | 1.8 | 2.0 | 2.2 | V | fCT=50kHz, fCT=120kHz |
| OSC Min voltage① | Voscl1 | 0.2 | 0.4 | 0.6 | V | fCT=50kHz |
| OSC Min voltage② | Voscl2 | 0.05 | 0.15 | 0.25 | V | fCT=120kHz |
| Soft start current | Iss | 0.50 | 1.00 | 1.50 | μA | |
| SRT ON resistance | RSRT | — | 150 | 300 | Ω | |
| ((BOSC BLOCK)) | | | | | | |
| BOSC Max voltage | VBCTH | 1.920 | 2.000 | 2.080 | V | fBCT=0.3kHz |
| BOSC Min Voltage | VBCTL | 0.400 | 0.500 | 0.600 | V | fBCT=0.3kHz |
| BOSC constant current | IBCT | 1.35/RT | 1.5/BRT | 1.65/RT | A | VBCT=0.2V |
| ((TIMER LATCH)) | | | | | | |
| Timer Latch voltage | Vscp | 1.8 | 2.0 | 2.2 | V | |
| Timer Latch current | Iscp | 0.25 | 0.50 | 0.75 | μA | |
| ((FEED BACK BLOCK)) | | | | | | |
| IS threshold voltage | Vis | 1.220 | 1.250 | 1.280 | V | |
| VS threshold voltage | Vvs | 1.220 | 1.250 | 1.280 | V | |
| IS source current 1 | Iis1 | — | — | 0.9 | μA | DUTY=2.0V |
| IS source current 2 | Iis2 | 12.0 | 20.0 | 28.0 | μA | DUTY=0V, IS=0.5V |
| VS source current | Ivs | — | — | 0.9 | μA | |
| FB over voltage detect voltage | Vovf | 2.2 | 2.5 | 2.8 | V | |
| IS COMP detect Voltage | Visc | 0.3 | 0.4 | 0.5 | V | |
| ((OUTPUT BLOCK)) | | | | | | |
| LN output sink current | RsinkLN | — | 15 | 30 | Ω | |
| LN output source current | RsourceLN | — | 30 | 60 | Ω | |
| HN output sink current | RsinkHN | — | 15 | 30 | Ω | VBST-VSW=5.0V |
| HN output source current | RsourceHN | — | 30 | 60 | Ω | VBST-VSW=5.0V |

(This product is not designed for normal operation with in a radio active environment.)

○Package Dimensions



○Block Diagram



○Pin Description

| Pin No. | Pin Name | Function |
|---------|----------|--|
| 1 | DUTY | Control PWM mode and BURST mode |
| 2 | BCT | External capacitor from BCT to GND for adjusting the BURST triangle oscillator |
| 3 | BRT | External resistor from BRT to GND for adjusting the BURST triangle oscillator |
| 4 | CT | External capacitor from CT to GND for adjusting the triangle oscillator |
| 5 | RT | External resistor from RT to GND for adjusting the triangle oscillator |
| 6 | SRT | External resistor from SRT to RT for adjusting the triangle oscillator |
| 7 | GND | GROUND |
| 8 | FB | Error amplifier output |
| 9 | IS | Error amplifier input① |
| 10 | VS | Error amplifier input② |
| 11 | STB | Stand-by switch |
| 12 | SCP | External capacitor from SCP to GND for Timer Latch |
| 13 | SS | External capacitor from SS to GND for Soft Start Control |
| 14 | PGND | Ground for FET drivers |
| 15 | LN | NMOS FET driver |
| 16 | HN | NMOS FET driver |
| 17 | SW | Low voltage for HN output |
| 18 | BST | Boot-Strap input for HN output |
| 19 | REG | Internal regulator output |
| 20 | VCC | Supply voltage input |

○NOTE FOR USE

1. When designing the external circuit, including adequate margins for variation between external devices and the IC. Use adequate margins for steady state and transient characteristics.
2. Recommended Operating Range
The circuit functionality is guaranteed within of ambient temperature operation range as long as it is within recommended operating range. The standard electrical characteristic values cannot be guaranteed at other voltages in the operating ranges, however, the variation will be small.
3. Mounting Failures
Mounting failures, such as misdirection or miscounts, may harm the device.
4. Electromagnetic Fields
A strong electromagnetic field may cause the IC to malfunction.
5. The GND pin should be the location within $\pm 0.3V$ compared with the PGND pin
6. BD9883AF, BD9883FV has the short circuit protection with Thermal Shut Down System. When STB or Vcc pin re-supplied, They enables to cancel the latch. If It rise the temperature of the chip more than 170°C(TYP), It make the external FET OFF
7. Absolute maximum ratings are those values that, if exceeded, may cause the life of a device to become significantly shortened. Moreover, the exact failure mode caused by short or open is not defined. Physical countermeasures, such as a fuse, need to be considered when using a device beyond its maximum ratings.
8. About the external FET, the parasitic Capacitor may cause the gate voltage to change, when the drain voltage is switching. Make sure to leave adequate margin for this IC variation.
9. On operating Slow Start Control (SS is less than 2.2V), It does not operate Timer Latch.
10. By STB voltage, BD9883AF, BD9883FV is changed to 2 states. Therefore, do not input STB pin voltage between one state and the other state (0.7~1.7V).

11. The pin connected a connector need to connect to the resistor for electrical surge destruction.
 12. This IC is a monolithic IC which (as shown is Fig-1)has P⁺ substrate and between the various pins. A P-N junction is formed from this P layer of each pin. For example, the relation between each potential is as follows,

- (When GND > PinB and GND > PinA, the P-N junction operates as a parasitic diode.)
- (When PinB > GND > PinA, the P-N junction operates as a parasitic transistor.)

Parasitic diodes can occur inevitably in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits as well as operation faults and physical damage. Accordingly you must not use methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND(P substrate)voltage to an input pin.

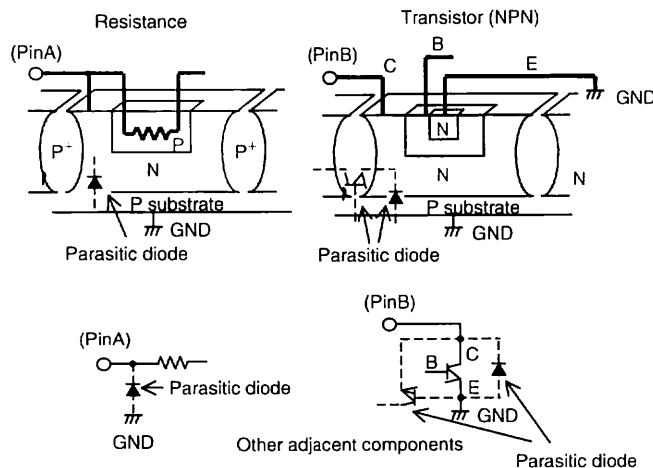


Fig-1 Simplified structure of a Bipolar IC

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